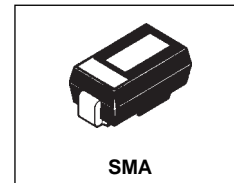


SCHOTTKY RECTIFIER

2.1 Amp



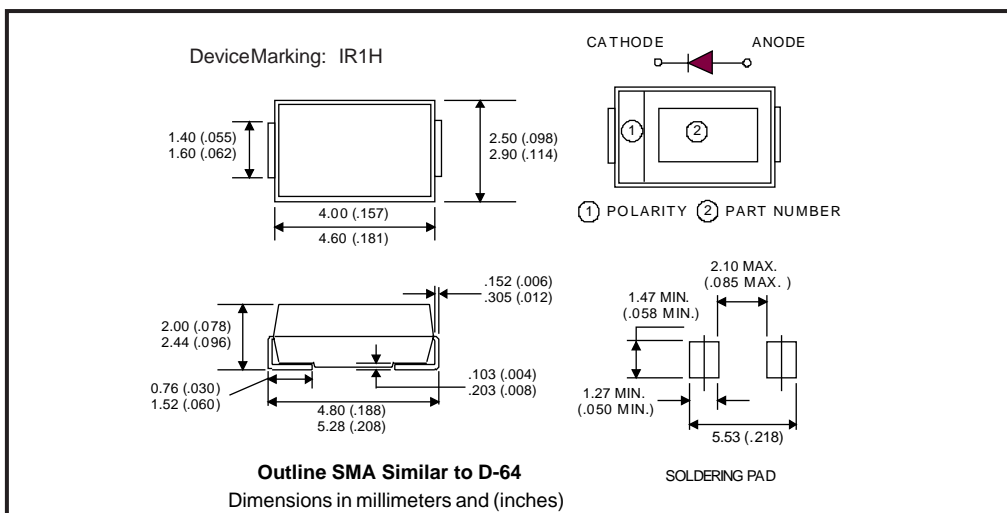
Major Ratings and Characteristics

Characteristics	10MQ060N	Units
$I_F$ DC	2.1	A
$V_{RRM}$	60	V
$I_{FSM}$ @ $t_p = 5 \mu s$ sine	40	A
$V_F$ @ 1.5Apk, $T_J = 125^\circ C$	0.63	V
$T_J$ range	-40 to 150	$^\circ C$

Description/Features

The 10MQ060N surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



### Voltage Ratings

Part number	10MQ060N
$V_R$ Max. DC Reverse Voltage (V)	60
$V_{RWM}$ Max. Working Peak Reverse Voltage (V)	

### Absolute Maximum Ratings

Parameters	10MQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 4	1.5	A	50% duty cycle @ $T_C = 120^\circ\text{C}$ , rectangular wave form On PC board 9mm <sup>2</sup> island (.013mm thick copper pad area)
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	40	A	5 $\mu$ s Sine or 3 $\mu$ s Rect. pulse
	10		10ms Sine or 6ms Rect. pulse
			Following any rated load condition and with rated $V_{RWM}$ applied

### Electrical Specifications

Parameters	10MQ	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop (1) * See Fig. 1	0.63	V	@ 1A
	0.71	V	@ 1.5A
	0.57	V	@ 1A
	0.63	V	@ 1.5A
			$T_J = 25^\circ\text{C}$
			$T_J = 125^\circ\text{C}$
$I_{RM}$ Max. Reverse Leakage Current (1) * See Fig. 2	0.5	mA	$T_J = 25^\circ\text{C}$
	7.5	mA	$T_J = 125^\circ\text{C}$
			$V_R = \text{rated } V_R$
$V_{F(TO)}$ Threshold Voltage	0.45	V	$T_J = T_J \text{ max.}$
$r_t$ Forward Slope Resistance	86.8	m $\Omega$	
$C_T$ Typical Junction Capacitance	31	pF	$V_R = 10V_{DC}$ ; $T_J = 25^\circ\text{C}$ ; test signal = 1Mhz
$L_S$ Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body

(1) Pulse Width < 300 $\mu$ s, Duty Cycle < 2%

### Thermal-Mechanical Specifications

Parameters	10MQ	Units	Conditions
$T_J$ Max. Junction Temperature Range	-40 to 150	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
$R_{thJA}$ Max. Thermal Resistance Junction to Ambient	160	$^\circ\text{C/W}$	DC operation
wt Approximate Weight	0.07(0.026)	g(oz.)	
Case Style	SMA		Similar D-64
Device Marking	IR1H		

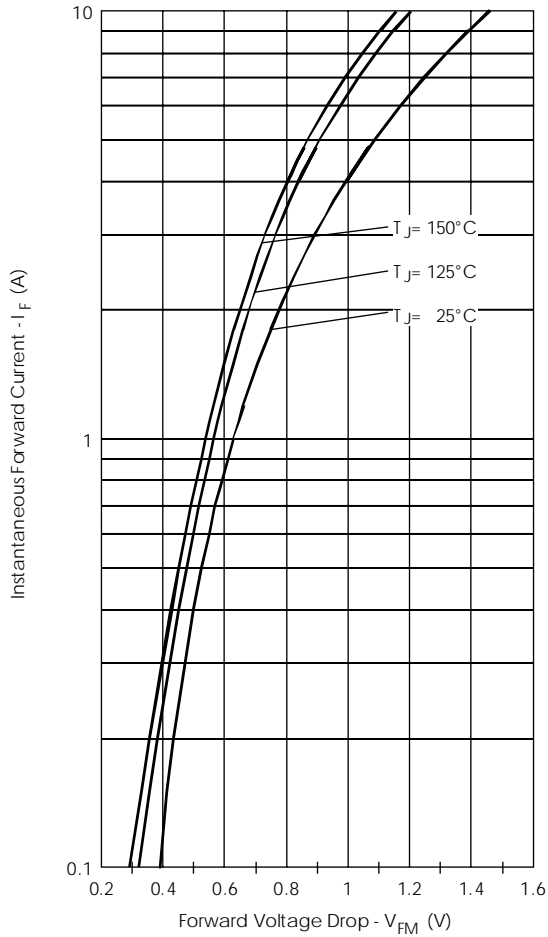


Fig. 1 - Maximum Forward Voltage Drop Characteristics

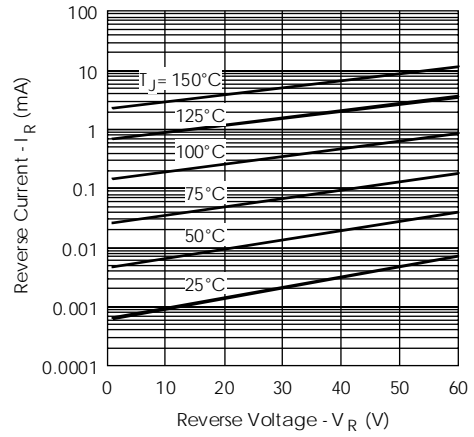


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

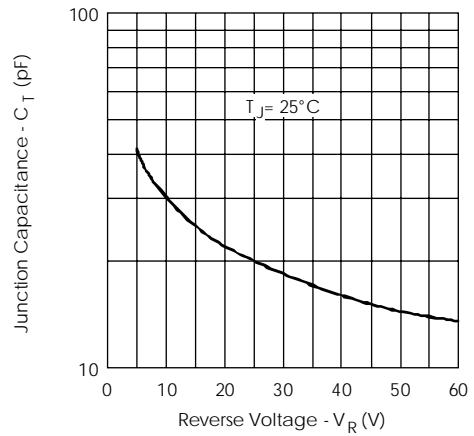


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

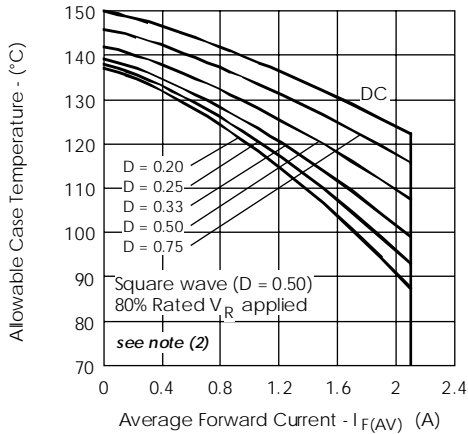


Fig. 4- Maximum Average Forward Current Vs. Allowable Lead Temperature

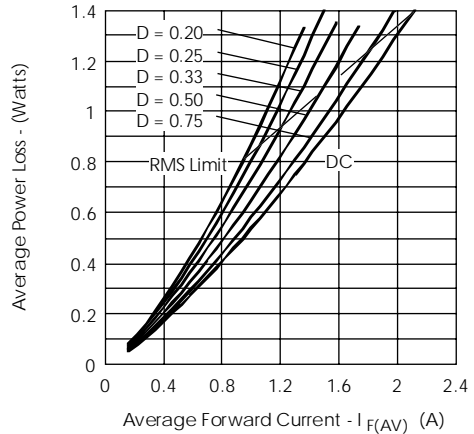


Fig. 5- Maximum Average Forward Dissipation Vs. Average Forward Current

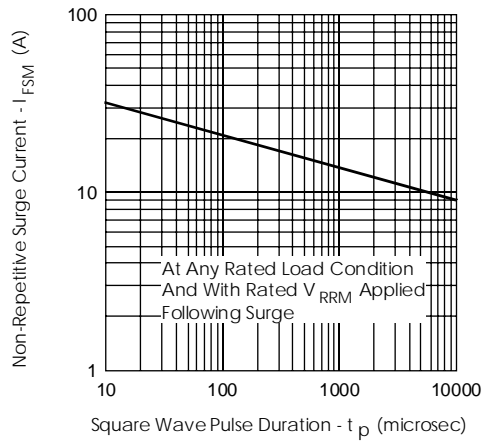


Fig. 6- Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used:  $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;

$P_d$  = Forward Power Loss =  $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);

$P_{d_{REV}}$  = Inverse Power Loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R @ V_{R1} = 80\%$  rated  $V_R$

Tape & Reel Information

